

CEN-U60
PNP SILICON
POWER TRANSISTOR



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CEN-U60 type is a PNP silicon power transistor designed for high voltage amplifier applications. This device is an electrical equivalent to Motorola's MPSU60.

MARKING: FULL PART NUMBER



TO-202 CASE

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Power Dissipation ($T_C=25^\circ\text{C}$)
Operating and Storage Junction Temperature
Thermal Resistance
Thermal Resistance

SYMBOL		UNITS
V_{CBO}	300	V
V_{CEO}	300	V
V_{EBO}	5.0	V
I_C	0.5	A
P_D	1.75	W
P_D	10	W
T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
θ_{JA}	70	$^\circ\text{C/W}$
θ_{JC}	12.5	$^\circ\text{C/W}$

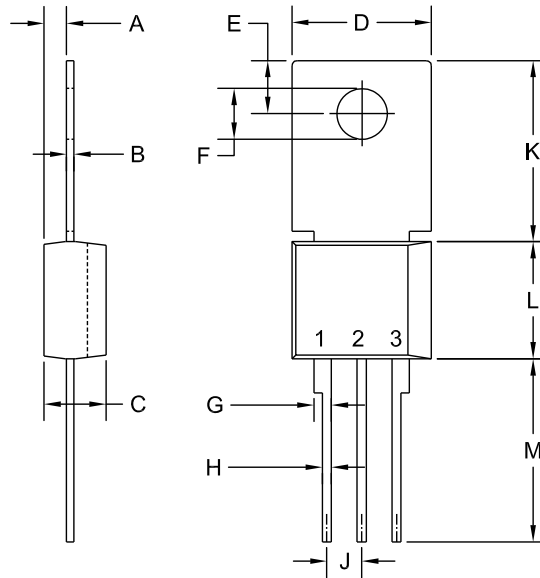
ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=200\text{V}$		0.2	μA
I_{EBO}	$V_{EB}=3.0\text{V}$		0.1	μA
BV_{CBO}	$I_C=100\mu\text{A}$	300		V
BV_{CEO}	$I_C=1.0\text{mA}$	300		V
BV_{EBO}	$I_E=10\mu\text{A}$	5.0		V
$V_{CE(SAT)}$	$I_C=20\text{mA}, I_B=2.0\text{mA}$		0.75	V
$V_{BE(SAT)}$	$I_C=20\text{mA}, I_B=2.0\text{mA}$		0.90	V
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{mA}$	25		
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	30		
h_{FE}	$V_{CE}=10\text{V}, I_C=30\text{mA}$	30		
f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	60		MHz
C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1.0\text{MHz}$		8.0	pF

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TO-202 CASE - MECHANICAL OUTLINE



R1

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector
- Tab is common to pin 3

MARKING:

FULL PART NUMBER

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.016	0.024	0.40	0.60
C	0.173	0.181	4.40	4.60
D	0.374	0.413	9.50	10.50
E	0.146	0.154	3.70	3.90
F (DIA)	0.142	0.150	3.60	3.80
G	0.039	0.055	1.00	1.40
H	0.024	0.031	0.60	0.80
J	0.094	0.106	2.39	2.69
K	0.492	0.551	12.50	14.00
L	0.327	0.346	8.30	8.80
M	0.492	0.531	12.50	13.50

TO-202 (REV: R1)

R0 (14-December 2011)